Temperature Sensor

Objective: Using BJT to make a circuit that can indicate the temperature.

In the shown circuit:

By Applying KVL:

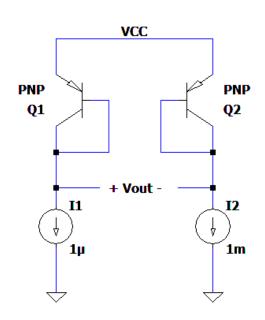
$$V_{out} = (V_{CC} - V_{BE1}) - (V_{CC} - V_{BE2})$$

$$V_{out} = V_{BE2} - V_{BE1}$$

From the BJT char. Eq. ($I_C = I_S e^{\frac{V_{BE}}{V_t}}$)

$$V_{BE} = V_t \ln(\frac{I_c}{I_s})$$
 So,

$$V_{out} = V_t \ln(\frac{I_{C2}}{I_{S2}}) - V_t \ln(\frac{I_{C1}}{I_{S1}})$$



 $V_{out} = V_t \ln(\frac{I_{C2} \times I_{S1}}{I_{S2} \times I_{C1}})$, Assuming the transistors are identical $(I_{S1} = I_{S2})$

And since $I_{C1}=I_1$, $I_{C2}=I_2$, $V_t=rac{KT}{q}$

$$V_{out} = \frac{KT}{q} \ln(\frac{I_2}{I_1}), \qquad V_{out} = \frac{K}{q} \ln(\frac{I_2}{I_1}) \times T$$

So the output of this circuit varies linearly with the temperature

but the value of the term $\frac{K}{q} \ln(\frac{I_2}{I_1})$ is small even after using a higher current ratio.

- 1. The output could be further amplified by using a simple differential amplifier circuit.
- 2. Or we could adjust the current ratio to get the desired output
- **4** Assume we want to represent the temperature as millivolts

So
$$\frac{K}{q} \ln \left(\frac{I_2}{I_1} \right) = \frac{1}{1000}$$
, ($\frac{K}{q} \approx 8.66 \times 10^{-5}$)

$$\ln\left(\frac{l_2}{l_1}\right) = 11.54$$
 , $\frac{l_2}{l_1} = 103501.78$ (if $I_1 = 0.1\mu A$)

Then $I_2 = 10.35 \text{mA}$

Then $V_{out} = T mV$ (T is in kelvin)